

March 1993 Revised September 2003

74LVX14

Low Voltage Hex Inverter with Schmitt Trigger Input

General Description

The LVX14 contains six inverter gates each with a Schmitt trigger input. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. In addition, they have a greater noise margin than conventional inverters.

The LVX14 has hysteresis between the positive-going and negative-going input thresholds (typically 1.0V) which is determined internally by transistor ratios and is essentially insensitive to temperature and supply voltage variations.

The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

Features

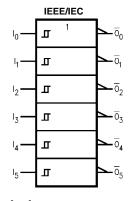
- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

Order Number	Package Number	Package Description
74LVX14M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LVX14SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX14MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

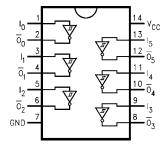
Logic Symbol



Pin Descriptions

Pin Names	Description
I _n	Inputs
\overline{O}_n	Outputs

Connection Diagram



Truth Table

Input	Output
Α	Ю
L	Н
Н	L

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC}) -0.5V to +7.0V

DC Input Diode Current (I_{IK})

 $\begin{array}{c} \text{V}_{\text{I}} = -0.5 \text{V} & -20 \text{ mA} \\ \text{DC Input Voltage (V}_{\text{I}}) & -0.5 \text{V to 7V} \end{array}$

DC Output Diode Current (I_{OK})

 $V_{O} = -0.5V$ -20 mA $V_{O} = V_{CC} + 0.5V$ +20 mA

-0.5V to $V_{CC} + 0.5$ V

DC Output Voltage (V_O)
DC Output Source

or Sink Current (I_O) ±25 mA

DC V_{CC} or Ground Current

 $(I_{CC} \text{ or } I_{GND})$ ±50 mA

Storage Temperature (T $_{STG}$) $-65^{\circ}C$ to $+150^{\circ}C$

Power Dissipation 180 mW

Recommended Operating Conditions (Note 2)

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions

for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	v _{cc}	T _A = +25°C			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions		
Symbol	Farameter	• 66	Min	Тур	Max	Min	Max	Offics	Conditions		
V _t +	Positive Threshold	3.0			2.2		2.2	V			
V _t -	Negative Threshold	3.0	0.9			0.9		V			
V _H	Hysteresis	3.0	0.3		1.2	0.3	1.2	V			
V _{OH}	HIGH Level	2.0	1.9	2.0		1.9			I _{OH} = -50 μA		
	Output Voltage	3.0	2.9	3.0		2.9		V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OH} = -50 \mu\text{A}$ $I_{OH} = -4 \text{ mA}$		
		3.0	2.58			2.48			$I_{OH} = -4 \text{ mA}$		
V _{OL}	LOW Level	2.0		0.0	0.1		0.1		$I_{OL} = 50 \mu A$		
	Output Voltage	3.0		0.0	0.1		0.1	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OL} = 50 \mu\text{A}$ $I_{OL} = 4 \text{ mA}$		
		3.0			0.36		0.44		$I_{OL} = 4 \text{ mA}$		
I _{IN}	Input Leakage Current	3.6			±0.1		±1.0	μΑ	V _{IN} = 5.5V or GND		
I _{CC}	Quiescent Supply Current	3.6			2.0		20	μΑ	V _{IN} = V _{CC} or GND		

Noise Characteristics (Note 3)

Symbol	Parameter	V _{CC}	T _A = 25°C		Units	C _L (pF)	
	Tarameter		Тур	Limit		OL (p.)	
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	3.3	0.3	0.5	V	50	
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	3.3	-0.3	-0.5	V	50	
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50	
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50	

Note 3: Input $t_f = t_f = 3ns$

AC Electrical Characteristics

Symbol	Parameter	v _{cc}	T _A = +25°C			T _A = -40°0	C to +85°C	Units	C _L (pF)	
Oymboi		(V)	Min	Тур	Max	Min	Max	Oilles	- L (P-)	
t _{PLH}	Propagation	2.7		8.7	16.3	1.0	19.5		15	
t_{PHL}	Delay Time	2.1		11.2	19.8	1.0	23.0	ns	50	
		3.3 ± 0.3		6.8	10.6	1.0	12.5	115	15	
		3.3 ± 0.3		9.3	14.1	1.0	16.0		50	
t _{OSLH}	Output to Output	2.7			1.5		1.5	ns	50	
toshl	Skew (Note 4)	3.3			1.5		1.5	113	30	

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

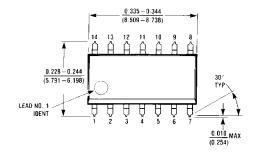
Capacitance

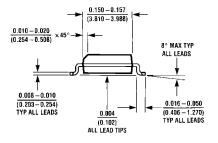
Symbol	Parameter		T _A = +25°C	;	T _A = -40°0	Units	
			Тур	Max	Min	Max	J.iita
C _{IN}	Input Capacitance		4	10		10	pF
C _{PD}	Power Dissipation		21				pF
	Capacitance (Note 5)		21				þг

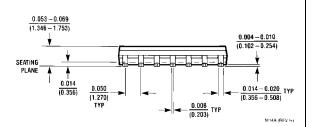
Note 5: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{|N} + I_{CC}}{6 \, (per \, Gate)}$

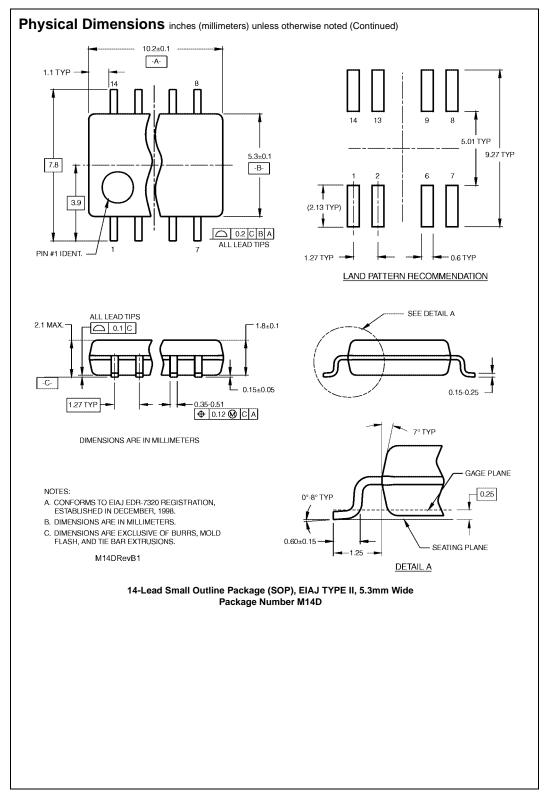
Physical Dimensions inches (millimeters) unless otherwise noted



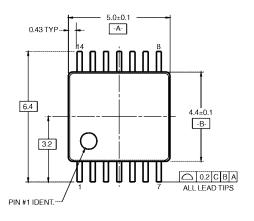


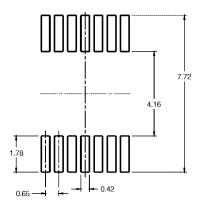


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Package Number M14A

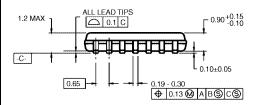


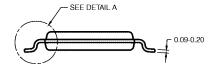
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





LAND PATTERN RECOMMENDATION

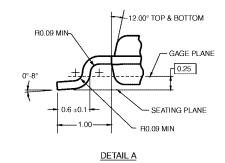




NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3



14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC14

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